

# Impact of the Synthesis Route on the Water Oxidation Kinetics of Hematite Photoanodes

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ABSTRACT: One	randa spectroelectrochemical	l analysis is used	to determine the		

: Operando spectroelectrochemical analysis is used to determine the water oxidation reaction kinetics for hematite photoanodes prepared using four different synthetic procedures. While these photoanodes exhibit very different current/voltage performance, their underlying water oxidation kinetics are found to be almost invariant. Higher temperature thermal annealing was found to correlate with a shift in the photocurrent onset potential toward less positive potentials, assigned to a suppression of both back electron-hole recombination and of charge accumulation in intra-bandgap states, indicating these intra-bandgap states do not contribute directly to water oxidation.



Photoelectrochemical water splitting is attracting extensive interest as a promising solar-to-fuel process to store solar energy in chemical bonds (i.e., hydrogen). In solar-driven water splitting, it is widely accepted that the oxygen evolution reaction (OER) is the most kinetically demanding process, especially when using earth abundant metal-oxide photoanodes.<sup>1,2</sup> Consequently, one of the primary limitations to efficiency in such photoanodes is the kinetic mismatch between the lifetimes of photogenerated charges, limited by recombination processes on picosecond to millisecond time scales, and the slow kinetics of OER catalysis, occurring usually on the millisecond to second time scale.3-5 The efficiency of such photoanodes is strongly dependent on not only the selection of metal oxide but also the methodology used to synthesize the photoanode, attributed to variations in nanomorphology, surface facet, doping, and surface state densities and surface/cocatalyst treatments.<sup>2</sup> However, it is often unclear whether such variations in photoelectrochemical performance result from differences in the underlying kinetics of OER catalysis or rather from differences in competing bulk or surface recombination processes. In this study, we address this issue for one of the most widely studied metal oxides for light driven oxygen evolving photoanodes, hematite ( $\alpha$ -Fe<sub>2</sub>O<sub>3</sub>). The kinetic mismatch between charge recombination and water oxidation is particularly severe in hematite. Consequently, analyzing the connection between overall performance and the underlying OER kinetics in hematite photoanodes synthesized by different deposition methods, yielding different morphologies, may inform strategies to further narrow the kinetic mismatch between reaction and recombination.

One of the key considerations for water oxidation on metal oxides, including hematite, is the potential role of intrabandgap surface states.<sup>6-9</sup> Such surface states have often been related to oxygen vacancies and structural imperfections/defect sites.<sup>10-12</sup> Surface holes on hematite have been assigned to Fe<sup>IV</sup>=O species, with these states being proposed as the first intermediate species of the OER.<sup>13</sup> Some studies, including electrochemical impedance analyses, have provided evidence that midgap surface states participate as intermediates in the OER catalysis on such photoanodes.<sup>14–17</sup> Other studies, including transient absorption analyses, have suggested OER catalysis is driven by valence band holes localized at the metal oxide surface, with intra-bandgap (e.g., oxygen vacancy) states primarily functioning as electron/hole trapping sites, impacting upon bulk and back electron-hole recombination.<sup>6,18-22</sup> The impact of surface states on the water oxidation catalysis on metal-oxide photoanodes such as  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> therefore remains controversial.

Herein we employ operando spectroelectrochemical analyses to determine the underlying OER kinetics on hematite photoanodes synthesized by four different methodologies. Despite exhibiting very different overall efficiencies for photoelectrochemical water oxidation, the underlying kinetics

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of water oxidation are almost independent of the synthetic route. In addition, we present evidence of parasitic optical signals arising from surface states in less active photoanodes but find that charge accumulation in these states does not drive OER catalysis. Rather the presence of such states is correlated with greater back electron—hole recombination processes, lowering photoanode performance.

In this study, hematite photoanodes were synthesized and subjected to different postdeposition annealing treatments: (i) 400 nm thick cauliflower Si-doped hematite synthesized by atmospheric pressure chemical vapor deposition (APCVD) at  $500 \circ \hat{C}_{1}^{23,24}$  (ii) flat 20 nm thick hematite deposited at 230 °C by atomic layer deposition (as-prepared ALD-AP),<sup>25</sup> (iii) identical ALD hematite film annealed at 600 °C (ALD-AN), and (iv) a dense solution-based regrown (SBR) film annealed at 800 °C.<sup>26</sup> For details on the deposition methods and physical characterization, please refer to the Supporting Information, Figures S1-S3. These films exhibit very different morphologies (with, for example, roughness factors ranging from 21 to 1.2), but all exhibit high crystallinity and the presence of the (110) crystal facet (see Supporting Information Figure S4). In common with many metal oxides, thermal annealing of hematite photoanodes is expected to reduce structural lattice disorder and drive the removal of oxygen vacancies and/or surface states as reported previously.27-29

Figure 1 shows the photoelectrochemical performance of the four hematite photoanodes studied herein. It is apparent that



Figure 1. Photoelectrochemical responses of the four hematite photoanodes studied herein. Normalized linear sweep voltammetries (10 mV s<sup>-1</sup>) of the (a) ALD as-prepared (ALD-AP, blue) and annealed (ALD-AN, red) and (b) APCVD (green) and solution-based regrown (SBR, purple) hematite photoanodes. Normalization performed at their photocurrent densities at 1.5 V vs RHE. (c) Non-normalized current densities at this 1.5 V bias. (d) Onset potentials for the water oxidation catalysis taken as the applied potential required to reach 1% of the photocurrent densities @ 1.5 V vs RHE. All data collected in three electrode PEC cell under chopped 1 sun illumination in 1 M NaOH.

the four films exhibit very different *JV* curves (Figure 1a,b) under 1 sun irradiation conditions (see Figure 1c and Figure S5 for non-normalized *JVs*). These photoanodes exhibit plateau photocurrent densities from ~0.4 to ~2.7 mA cm<sup>-2</sup> at 1.5 V vs RHE (i.e., bias conditions where negligible back electron-hole recombination and no dark catalysis occur), in agreement with previous reports in the literature.<sup>23,25,26</sup> The

two ALD films generate ~1 order of magnitude lower photocurrent densities, most likely due to their lower light absorption and lower exposed surface area (roughness factor) compared to the APCVD and SBR films. Panels a and b of Figure 1 also show less prominent cathodic current spikes for both SBR (purple) and ALD-AN (red) photoanodes compared to the APCVD (green) and ALD-AP (blue) samples observed under chopped light excitation. Such cathodic spikes have previously been associated with back electron—hole (surface) recombination processes.<sup>21,30,31</sup> Their suppression in the SBR and ALD-AN films correlates with their earlier (less positive) photocurrent onset potentials, <0.9 V vs RHE (see Figure 1d), with the SBR photoanodes exhibiting an onset of 0.7 V vs

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photoanodes without cocatalyst treatments.<sup>26,32,33</sup> To determine the underlying OER kinetics on these photoanodes, spectroelectrochemical rate law analyses were employed to determine the reaction orders and water oxidation rate constants ( $k_{WO}$ ) for each photoanode. These *operando* spectroelectrochemical photoinduced absorption (SEC-PIA) measurements, taken as a function of light intensity, were analyzed using the following equation, in accordance with a procedure previously reported by our group.<sup>34,35</sup>

RHE, close to the state-of-the-art reported for hematite

$$I^{\rm ph} = k_{\rm WO} \cdot (p_{\rm s}^+)^{\alpha} \tag{1}$$

where  $J^{\rm ph}$  corresponds to the water oxidation reaction rate, measured by the steady-state photocurrent density and  $p_s^+$ corresponds to the density of surface holes (Fe<sup>IV</sup>=O states) accumulated at the photoanode surface, as measured by their optical absorbance at 650 nm<sup>34</sup> (this spectral assignment is discussed further below). Log/log plots  $J^{\rm ph}$  versus  $p_s^+$  are shown in Figure 2 and allow determination of apparent reaction rate constants,  $k_{\rm WO}$ , and reaction orders,  $\alpha$ , with respect to surface hole density. As we have discussed previously, this analysis



**Figure 2.** Log/log plot of the water oxidation photocurrent density vs the surface hole density measured at 1.5 V vs RHE in 1 M NaOH electrolyte of the APCVD (green), SBR (purple), ALD–AP (blue), and ALD-AN (red) hematite photoanodes. The surface hole density was converted from the optical absorption at 650 nm using a hole extinction coefficient value of 640  $M^{-1}$  cm<sup>-1</sup> (for details on the extinction coefficient determination, please refer to SI Figure S6). The data have been corrected for the roughness factor, 1.2 reported for the ALD,<sup>25</sup> 21 reported for the APCVD,<sup>23</sup> and 1.7 measured herein for the SBR films. All dashed lines are fitted to a gradient of 3.

assumes for simplicity, that all surface valence band holes accumulating under these conditions have similar enthalpies, with increases in water oxidation rate with higher light intensity or more anodic bias being assigned to increases in the density of these species, yielding an increased optical absorption.

It is apparent from Figure 2 that all four photoanodes show remarkably similar water oxidation reaction kinetics. This contrasts with their markedly different overall *IV* performance (Figure 1). All four photoanodes exhibit a third order of reaction ( $\alpha \sim 3$ ) with respect to surface hole density (with  $\alpha$ determined from the line gradients in Figure 2), as we have previously reported for the APCVD  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> film.<sup>34</sup> Such third-order behavior has also been observed for BiVO<sub>4</sub><sup>36</sup> and TiO<sub>2</sub><sup>37</sup> photoanodes and has been suggested to be indicative of the rate-determining step (RDS) in water oxidation requiring the equilibrium of three surface holes with the reaction center.<sup>38</sup> Third-order kinetics are observed for all photoanodes, despite exhibiting turn on potentials differing by up to 200 mV and saturating photocurrent densities ranging by an order of magnitude. Third-order rate constants for the OER,  $k_{WO}$ , are found to follow the trend ALD-AN > SBR  $\approx$  APCVD > ALD-AN. Interestingly, such a trend coincides with the observed back electron-hole recombination losses observed in the IV curves (Figure 1a,b), suggesting that lower photoanodes performance are primarily determined by recombination losses.

Figure 2 shows that the ALD-AP photoanode exhibits an approximately 3-fold lower  $k_{WO}$  than the ALD-AN photoanode. To further investigate this difference, log/log plots of  $J^{\rm ph}$  versus  $p_{\rm s}^+$  were collected as a function of applied potential (Figure 3a,b and Figure S7). At less positive applied potentials, higher light intensities were required to achieve equivalent photocurrent densities for all four photoanodes, attributed to enhanced recombination losses. However, plots of the accumulated surface hole density (i.e., PIA signal at 650 nm) against photocurrent for the three more efficient photoanodes



**Figure 3.** Rate law and photoinduced spectra as a function of applied bias for water oxidation on ALD  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> photoanodes. Log/log plots of the water oxidation photocurrent density ( $J^{\rm ph}$ ) vs surface hole density of the (a) ALD-AN (red) and (b) ALD-AP (blue)  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> films as a function of applied potential (1.15, 1.3, and 1.5 V vs RHE). Steady-state PIA spectra of the (c) ALD-AN (red), measured at 0.8, 1.0, 1.15, and 1.5 V vs RHE, and (d) ALD-AP (blue), measured at 0.85, 1.15, 1.3, and 1.5 V vs RHE,  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> films under 1 sun illumination in 1 M NaOH.

(Figure 3a and Figure S7) show that observed photocurrent densities are essentially independent of applied potential (a small dependence is observed for the APCVD photoanode, Figure S7). Thus, the differences in IV performance apparent in Figure 1 do not result from differences in the underlying OER kinetics, but rather from the differences in their light absorption and charge separation/recombination kinetics as commented above. This striking observation implies that the effect of a more positive applied potential is mainly to improve the ability of the photoanode to accumulate holes at the surface, by turning off recombination, without changing the underlying OER kinetics. This supports the validity of our rate law analysis (eq 1), which assumes that the water oxidation flux is primarily determined by the density of accumulated surface Fe<sup>IV</sup>=O species, rather than changes in the Fe<sup>IV</sup>=O energetics or changes in potential drops across the depletion/Helmholtz layers. In contrast, for the lower performance ALD-AP photoanodes, Figure 3b shows a clear bias dependence of photocurrent density versus 650 nm PIA signal. This implies that for matched optical signal amplitudes, the water oxidation flux for this photoanode becomes smaller at less positive potentials, in contrast to the behavior observed for the more efficient photoanodes (Figure 3a and Figure S7).

To further investigate the difference between the ALD-AP and other photoanodes, normalized steady-state PIA spectra are shown in Figure 3c,d for the ALD-AN and ALD-AP photoanodes, respectively, plotted as a function of applied potential at a fixed irradiation intensity (1 sun). The ALD-AN photoanode exhibits a single broad absorption, peaking between 600 and 650 nm, whose spectral shape is largely independent of applied potential (Figure 3c). As discussed above, this 650 nm absorption feature has previously been assigned to accumulated surface holes driving water oxidation.34 This observation indicates that the chemical nature of the holes accumulating under irradiation on these photoanodes is independent of the applied potential. In contrast, the PIA spectra observed for the ALD-AP photoanodes show an additional narrow, absorbance (Figure 3d), centered at 580 nm, that becomes relatively more dominant at less positive applied potentials. Analogous, but less pronounced bias dependent PIA spectra were also observed for the APCVD and SBR photoanodes (Figure S7b). The additional absorption peak resembles a 580 nm spectral feature previously assigned to some extent to oxidation of oxygen vacancy  $(V_0)$  states in the space charge layer of APCVD hematite films and is therefore tentatively assigned to these states. We note that such 580 nm absorption has been alternatively assigned in ref 39 to surface states driving water oxidation. However, a complete study of this spectral feature is beyond the scope of this letter. We also note that the emergence of this spectral feature coincides with a loss of photocurrent density for matched 650 nm absorbance. This can be most readily understood as resulting from the 580 nm absorption feature overlapping with valence band hole absorbance at 650 nm, with these intra-bandgap states not contributing to the OER or photocurrent generation. The PIA data thus indicate that in addition to photoinduced valence band hole accumulation driving water oxidation, the accumulation of oxidized intra-bandgap states in the space charge layer can also be observed. Optical signals from these oxidized states accumulation are most prominent in less efficient photoanodes and at less positive potentials, indicating such oxidized intragap states are relatively inactive in driving

water oxidation, but rather act as a photocurrent loss mechanism. The influence of this parasitic signal in the 650 nm hole absorption, caused by these intra-bandgap states, can be observed by correlating the transient 650 nm absorption amplitude after 100 ms of a 6 ns laser photoexcitation (see Figure S8 and corresponding discussion in the Supporting Information). This further supports the observation of an almost invariant water oxidation underlying kinetics on hematite photoanodes with lower photoanode performance deriving mainly from enhanced recombination losses.

In summary, we find that the kinetics of driving water oxidation by hematite valence band holes are remarkably independent of the film synthesis route and nanomorphology, at least for the photoanodes studied herein. This independence is consistent with our previous studies, which indicate that the rate-determining step for water oxidation on hematite is driven by the localized accumulation of three Fe<sup>IV</sup>==O surface holes, without the need for the presence of specific catalytic sites.<sup>38</sup> As such, differences in photoelectrochemical OER performance of these photoanodes does not derive primarily for differences in OER kinetics, but rather from differences in light absorption and competing charge recombination/trapping pathways. In addition, as illustrated in Figure 4, for less



**Figure 4.** Simplified schematic representation water oxidation on the four  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> photoanodes studied herein. Filled/empty circles representing reduced/oxidized intra-bandgap states. Thermally annealing in air is expected to reduce the density of these states, correlated with more efficient water oxidation. See details of HR-TEM and SEM images in Supporting Information Figure S2.

positive applied potentials, optical signals can be observed in three of our studied photoanodes, indicative of charge accumulation in intra-bandgap states. Charge accumulation in such intra-bandgap states has previously been reported for hematite in several studies and proposed to drive water oxidation.<sup>14–17</sup> In contrast, the data herein shows that charge accumulating in these states does not contribute significantly to water oxidation, most likely due to their modest oxidation potentials relative to hematite's valence band. These intrabandgap states have been suggested to be catalytically inactive,<sup>40</sup> instead, they are likely involved in competing trapping processes that can be mitigated with increasing applied potentials. These intra-bandgap states have been shown by photoelectrochemical impedance spectroscopy means to correlate with the photocurrent onset potential, on ultraspray pyrolysis hematite, upon their oxidation by increasing the applied potential.<sup>41</sup> The presence of such midgap states results in apparent potential dependence of kinetics of water oxidation (due to increased charge accumulation in these inactive states at lower potentials); in the absence of such states, the water oxidation rate constant is independent of applied potential. Our results also confirm that on efficient photoelectrodes, the acceleration of water oxidation kinetics at high light levels is determined by surface valence band hole accumulation rather than changes in potential drops across the depletion or Helmholtz layers. Intra-bandgap states are associated with surface (back electron/hole) recombination losses, as illustrated in Figure 4, and supported by more prominent cathodic current spikes in Figure 1 and consequently more positive photocurrent onset potentials. In summary, we conclude that the primary determinant of water oxidation flux, independent of photoanode synthesis route and applied bias, is the density of  $Fe^{IV}$  = O holes accumulated at the photoanode surface.

## ASSOCIATED CONTENT

## **Supporting Information**

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/acs.jpclett.0c02004.

Details on the hematite photoanodes synthesis, UV-vis spectra, SEM and XRD characterization, roughness factor determination, PEC characterization details, SEC-PIA, hole extinction coefficient determination, rate law and steady-state spectra, and TAS details and supporting figures (PDF)

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#### Notes

The authors declare no competing financial interest.

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